

MAX 108 segments (SEG27×COM4) Standard LCD Segment Drivers

BU9795AFV-LB

This is the product guarantees long time support in Industrial market.

Features

- Long Time Support Product for Industrial Applications.
- Integrated RAM for Display Data (DDRAM) : 35 × 4bit
- LCD Drive Output : 4 Common Output, 27Segment Output
- Integrated Buffer AMP for LCD driving
- Integrated Oscillator Circuit
- No External Components
- Low Power Consumption Design

Applications

- Industrial Equipment
- Telephone
- FAX
- Portable Equipment (POS, ECR, PDA etc.)
- DSC
- DVC
- Car Audio
- Home Electrical appliance
- Meter Equipment

Etc.

Typical Application Circuit

Key Specifications

- Supply Voltage Range:
 - +2.5V to +5.5V **Operating Temperature Range:** -40°C to +85°C
- Max Segments:BU9795AFV-LB
- Display Duty:
- Bias:
- Interface:

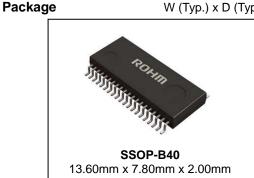
W (Typ.) x D (Typ.) x H (Max.)

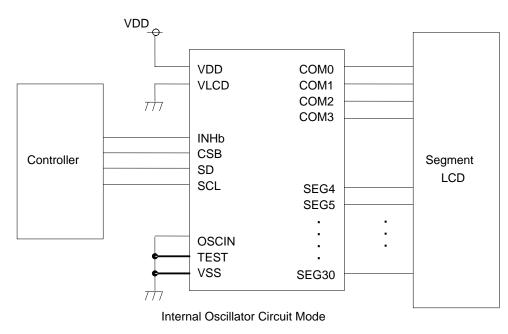
108 Segments

1/2, 1/3 Selectable

3wire Serial Interface

1/4





Typical application circuit Figure 1.

OProduct structure : Silicon monolithic integrated circuit OThis product has no designed protection against radioactive rays.

Block Diagrams / Pin Configurations / Pin Descriptions

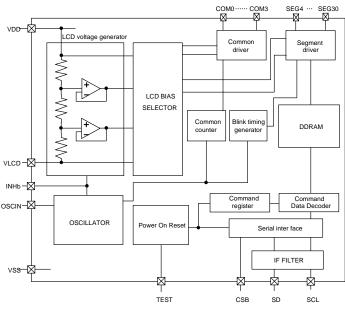


Figure 2. Block Diagram

 Image: Non-Section 2014
 Image: Non-Sec SEG7 SEG6 SEG5 SEG4 TEST A A A 40 1 BOBS SEG9 SEG19 SEG22 111 SEG23 111 SEG24 111 SEG25 SEG14 SEG15 H E E SEG12 E SEG16 SEG17 E Ħ E 20 SEG10 SEG11 SEG13 SEG18 SEG20 SEG21 SEG26 EG27

Figure 3. Pin Configuration (TOP VIEW)

Table 1 Pin Description

Pin Name	Pin No.	I/O	Function
INHb	36	Ι	Input terminal for turn off display H : turn on display L : turn off display
TEST	35	Ι	Test input (ROHM use only) Must be connected to VSS
OSCIN	31	Ι	External clock input Ext. clock and Int. clock can be changed by command. Must be connected to VSS when using internal oscillation circuit.
SD	34	Ι	Serial data input
SCL	33	Ι	Serial data transfer clock
CSB	32	Ι	Chip select : "L" active
VSS	30		GND
VDD	29		Power supply
VLCD	28	Ι	Power supply for LCD driving
SEG4 to 30	1 to 23, 37 to 40	0	SEGMENT output for LCD driving
COM0 to 3	24 to 27	0	COMMON output for LCD driving

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BU9795AFV-LB

Absolute Maximum Ratings (VSS=0V)

Parameter	Symbol	Ratings	Unit	Remark
Power Supply Voltage1	VDD	-0.5 to +7.0	V	Power supply
Power Supply Voltage2	VLCD	-0.5 to VDD	V	LCD drive voltage
Power Dissipation	Pd	0.7	W	When use more than Ta=25°C, subtract 7mW per degree (BU9795AFV-LB) (Package only)
Input Voltage Range	VIN	-0.5 to VDD+0.5	V	
Operational Temperature Range	Topr	-40 to +85	°C	
Storage Temperature Range	Tstg	-55 to +125	°C	

Caution:Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circui between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Recommended Operating Conditions (Ta=-40°C to +85°C, VSS=0V)

	Symbol		Ratings		Unit	Remark
Parameter	Symbol	Min	Тур	Max	Unit	Remark
Power Supply Voltage1	VDD	2.5	-	5.5	V	Power supply
Power Supply Voltage2	VLCD	0	-	VDD -2.4	V	LCD drive voltage

(Note) Please use VDD-VLCD≥2.4V condition.

Electrical Characteristics

DC Characteristics (VDD=2.5V to 5.5V, VSS=0V, Ta=-40°C to +85°C, unless otherwise specified)

Parameter		Symbol		Limits		Unit	Conditions		
Falameter		Symbol	Min	Тур	Max	Unit	Conditions		
"H" Level Input Voltage	е	VIH	0.7VDD	-	VDD	V			
"L" Level Input Voltage	9	VIL	VSS	-	0.3VDD	V			
"H" Level Input Currer	nt	IIH	-	-	1	μA			
"L" Level Input Curren	t	IIL	-1	-	-	μA			
LCD Driver	SEG	RON	-	3.5	-	kΩ	lload=±10µA		
on Resistance	COM	RON	-	3.5	-	kΩ			
VLCD Supply Voltage		VLCD	0	-	VDD -2.4	V	VDD-VLCD≥2.4V		
Standby Current		lst	-	-	5	μA	Display off, Oscillator off		
Power Consumption1	ver Consumption1		sumption1 IDE		-	12.5	30	μA	VDD=3.3V, Ta=25°C, Power save mode1, FR=70Hz 1/3 bias, Frame inverse
Power Consumption2		IDD2	-	20	40	μA	VDD=3.3V, Ta=25°C, Normal mode, FR=80Hz 1/3 bias, Line inverse		

Electrical Characteristics - continued

Oscillation Characteristics (VDD=2.5V to 5.5V, VSS=0V, Ta=-40°C to +85°C)

Parameter	Symbol		Limits		Unit	Conditions	
Falameter	Symbol	Min	Тур	Max	Unit	Conditions	
Frame Frequency	fclk	56	80	104	Hz	FR = 80Hz setting	
Frame Frequency1	fclk1	70	80	90	Hz	VDD=3.5V, 25°C	

MPU interface Characteristics (VDD=2.5V to 5.5V, VSS=0V, Ta=-40°C to +85°C)

Parameter	Symbol		Limits		Unit	Conditions
Falameter	Symbol	Min	Тур	Max	Unit	Conditions
Input Rise Time	tr	-	-	80	ns	
Input Fall Time	tf	-	-	80	ns	
SCL Cycle Time	tSCYC	400	-	-	ns	
"H" SCL Pulse Width	tSHW	100	-	-	ns	
"L" SCL Pulse Width	tSLW	100	-	-	ns	
SD Setup Time	tSDS	20	-	-	ns	
SD Hold Time	tSDH	50	-	-	ns	
CSB Setup Time	tCSS	50	-	-	ns	
CSB Hold Time	tCSH	50	-	-	ns	
"H" CSB Pulse Width	tCHW	50	-	-	ns	

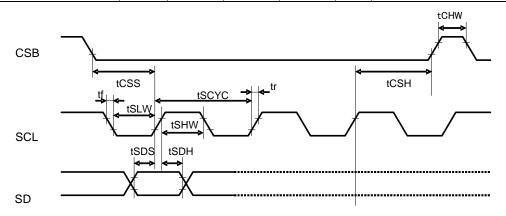


Figure 4. Interface Timing

I/O Equivalence Circuit

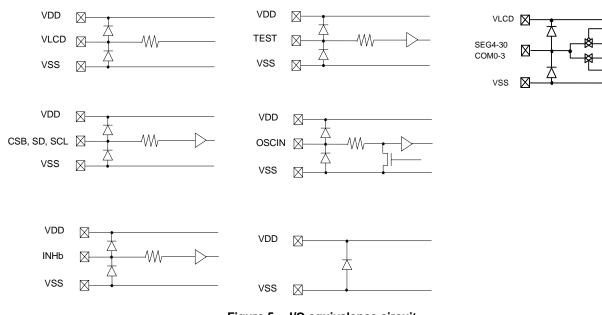
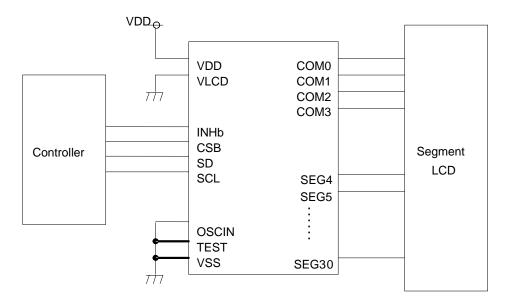
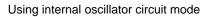


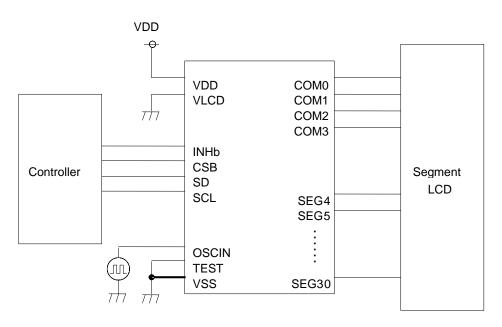
Figure 5. I/O equivalence circuit

Example of Recommended Circuit

<BU9795AFV-LB>







Using external oscillator mode

Figure 6. BU9795AFV example recommended circuit

Function Description

Command and data transfer method

3-SPI (3wire Serial interface)

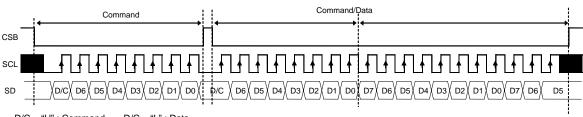
This device is controlled by 3-wire signal (CSB, SCL, and SD).

First, Interface counter is initialized with CSB="H", and CSB="L" makes SD and SCL input enable.

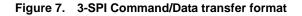
The protocol of 3-SPI transfer is as follows.

Each command starts with Command or Data judgment bit (D/C) as MSB data, followed by D6 to D0 during CSB ="L".

(Internal data is latched at the rising edge of SCL, it is converted to 8bits parallel data at the falling edge of 8th CLK.)



D/C = "H": Command D/C = "L": Data



Command transfer method

After CSB="H" \rightarrow "L", 1st byte is always a command input.

MSB of the command input data will be judged that the next byte data, it is a command or display data (This bit is called

"command or data judgment bit").

When set "command or data judge bit"='1', next byte will be (continuously) command.

When set "command or data judge bit"='0', next byte data is display data.

	1	Command	1	Command	1	Command	0	Command	Display Data	
--	---	---------	---	---------	---	---------	---	---------	--------------	--

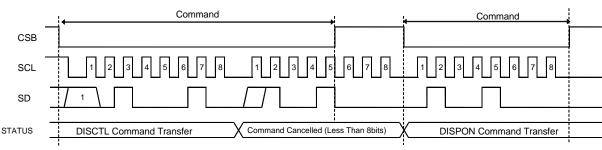
Once it becomes display data transfer condition, it will not be back to command input condition even if D/C=1. So if you want to send command data again, please set $CSB="L" \rightarrow "H"$.

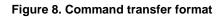
(CSB "L" \rightarrow "H" will cancel data transfer condition.)

Command transfer is done by 8bits unit, so if $CSB="L" \rightarrow "H"$ with less than 8bits data transfer, command will be cancelled.

It will be able to transfer command with CSB="L" again.

In Case Of Command Transfer





Write display data and transfer method

<BU9795AFV-LB>

```
This LSI has Display Data RAM (DDRAM) of 27×4=108bit.
As SEG0, SEG1, SEG2, SEG3, SEG31, SEG32, SEG33, SEG34 are not output, these address will be dummy address.
The relationship between data input and display data. DDRAM data and address are as follows.
```

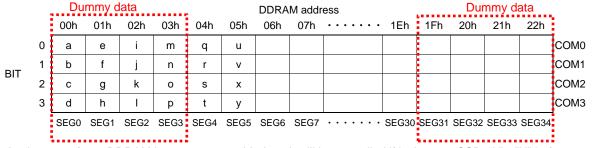
The relationship between data input and display data, DDRAM data and address are as follows.

Command																									
0000000	a	b	с	d	е	f	g	h	i	j	k	I	m	n	0	р	q	r	s	t	u	v	x	у	
	•	↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓								->			Di	ispl	i ay I	l Data	i a	1							

8 bit data will be stored in DDRAM. The address to be written is the address specified by ADSET command, and the address is automatically incremented in every 4bit data.

Data can be continuously written in DDRAM by transmitting Data continuously.

(When RAM data is written successively after writing RAM data to 22h (SEG34), the address is returned to 00h (SEG0) by the auto-increment function.



As data transfer to DDRAM happens every 4bit data, it will be cancelled if it changes CSB="L" \rightarrow "H" before 4bits data transfer.

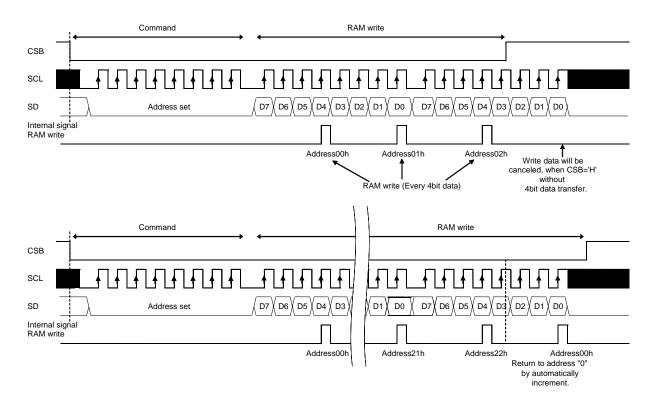
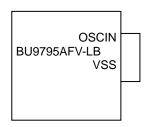


Figure 9. BU9795AFV-LB Data Transfer Format

OSCILLATOR

There are two kinds of clock for logic and analog circuit; from internal oscillator circuit or external clock input. If internal oscillator circuit will be used, OSCIN must be connected to VSS.

(Note) When you use external clock, execute ICSET command and connect OSCIN to external clock.



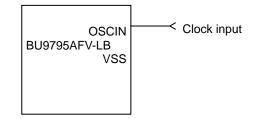


Figure 10. Internal oscillator circuit mode



LCD Driver Bias Circuit

This LSI generates LCD driving voltage with on-chip Buffer AMP. And it can drive LCD at low power consumption. 1/3 and 1/2Bias can be set in MODESET command. Line and frame inversion can be set in DISCTL command.

Refer to "LCD driving waveform" about each LCD driving waveform.

Blink timing generator

This device has Blinking function.

This LSI is able to set blink mode with BLKCTL command.

Blink frequency varies widely by characteristic of fCLK, when internal oscillation circuit.

Refer to Oscillation Characteristics for more details on fCLK.

Reset (initial) condition

Initial condition after execute SOFTWARE RESET is as follows.

· Display is OFF.

· DDRAM address is initialized (DDRAM Data is not initialized).

Refer to Command Description about initialize value of register.

Command / Function List

Description List of Command / Function

No.	Command	Function
1	Mode Set (MODESET)	Set LCD drive mode
2	Address Set (ADSET)	Set LCD display mode 1
3	Display Control (DISCTL)	Set LCD display mode 2
4	Set IC Operation (ICSET)	Set IC operation
5	Blink Control (BLKCTL)	Set blink mode
6	All Pixel Control (APCTL)	Set pixel condition

Detailed Command Description

D7 (MSB) is bit for command or data judgment. Refer to Command and data transfer method.

C: 0: Next byte is RAM write data.

C: 1: Next byte is command.

(1) Mode Set (MODE SET)

INIOD							LOD
D7	D6	D5	D4	D3	D2	D1	D0
С	1	0	*	P3	P2	*	*

(* : Don't care)

Set display ON and OFF

Setting	P3	Reset initialize condition
Display OFF(DISPOFF)	0	0
Display ON(DISPON)	1	

Display OFF : Regardless of DDRAM data, all SEGMENT and COMMON output will be stopped after 1 frame of data write. Display OFF mode will be finished by Display ON.

Display ON : SEGMENT and COMMON output will be active and start to read the display data from DDRAM.

(Note) It is not synchronize with display frame, when it will be controlled display ON/OFF with INHb terminal.

Set bias level

Setting	P2	Reset initialize condition
1/3 Bias	0	0
1/2 Bias	1	

Refer to LCD driving waveform.

(2) Address set (ADSET)

MSB							LSB
D7	D6	D5	D4	D3	D2	D1	D0
С	0	0	P4	P3	P2	P1	P0

Address data is specified in P [4:0] and P2 (ICSET command) as follows.

	MSB		LSB
Internal register	Address [5]	Address [4]	 Address [0]
Bit of each command	ICSET [P2]	ADSET [P4]	 ADSET [P0]

.

The address is 00h in reset condition. The valid address is 00h to 22h. Another address is invalid, (otherwise address will be set to 00h.) P2 of ICSET command is only to define either MSB of address is "1" or "0". Address counter will be set only when ADSET command is executed.

CSB													
MMAND	ADSET	"00010" (RAM	Write RAM Write	RAM Write			RAM Write	X	DISCTL X	RAM Write	RAM Write	R	AM Write
nal Signal SET P2													
nal Signal ddress		000010	000011 00	0100	100010	000000	000001	000010 个			11 X 000	0100	000101
	P2 (ICSET	command)	Γ command. is refer to set a l0010", because		I data is contir be incremen at 22h addre	t automatica ss, address	ally.		Because of it will be ke It will be sta ng address	pt the previo art to write F	ous addre RAM data	ss. from m	aintained a
CSB] Adset	"11111 RAM	Write RAM Write	RAM Write			RAM Write		DSET"0000	'RAM Write	RAM Write	R	AM Write
nal Signal SET P2													
nal Signal ddress		011111	100000 10	0001 🗙 10001	0 000000	000001	000010	000011 个	<u>)</u> 0000	000 0000	101 X 000	0010	000011
	P2(ICSET	command)	F command. s refer to set ad 1111", because		"O"				New a	address will	be set by	ADSE	T comman
				addres When v return t	write at 22h a to 00h autom	address, ad							
		P2=1 ADSET	000000 RAM Write	When y return t	write at 22h a	address, ad		L	\DSET"00000"	RAM Write)	RAM Write	<u>R</u>	AM Write
MMAND]XICSET	P2=1 XADSET	20000) RAM Write	When y return t	write at 22h a	address, ad	dress will be	L	\DSET"00000"X	RAM Write	RAM Write	<u>R</u>	AM Write
MMAND nal Signal SET P2 nal Signal	L	P2=1 VADSET		When y return t	write at 22h a to 00h autom	address, add natically.	dress will be	000011	\\\\\\\\	^			AM Write
CSB MMAND nal Signal SET P2 nal Signal ddress) XICSET	Set ac P2(IC		When return t	write at 22h a to 00h autorr	address, add natically.	RAM Write	000011	↓ 1000 ↑ New address wi (P2(ICSET)	ss will be se ll be set "10) will mainta	ot by ADSI 00000", be ain the pre	ET com	000000 Imand. P2(ICSET)
MMAND nal Signal SET P2 nal Signal Idress		Set ac P2(IC: Addre	100000 10 Idress by ADSE BET command) ss will be set "1 ET command.	When 1 return 1 (RAM Write 00001 (10001 T command. is refer to set 00000°, beca 00000°, beca When 1 addres When 1	write at 22h a to 00h autorr	T)="1".	RAM Write)	000011	↓ 1000 ↑ New addre: Address wi	ss will be se ll be set "10) will mainta command	ot by ADSI 00000", be in the pre input.	ET com cause f vious a	000000 Imand. P2(ICSET, ddress
MMAND nal Signal SET P2 nal Signal Idress It w (IC3	ill be set P2	Set ac P2(IC: Addre	100000 10 Idress by ADSE BET command) ss will be set "1 ET command.	When 1 return 1 (RAM Write 00001 (10001 T command. is refer to set 00000°, beca 00000°, beca When 1 addres When 1	write at 22h a to 00h autorr 0 0 000000 address use P2(ICSE RAM data is s will be incr	T)="1".	RAM Write)	000011	↓ 1000 ↑ New address wi (P2(ICSET) until ICSET	ss will be se ll be set "10) will mainta command	ot by ADSI 00000", be in the pre input.	ET com cause f vious a	000000 Imand. P2(ICSET) ddress
MMAND hal Signal SET P2 hal Signal Idress	ill be set P2 SET comma	Set ac P2(IC: Addre	100000 10 Idress by ADSE SET command) Ss will be set "1 ET command. et address)	When 1 return 1 (RAM Write 00001 (10001 T command. is refer to set 00000°, beca 00000°, beca When 1 addres When 1	write at 22h a to 00h autorr 0 0 000000 address use P2(ICSE RAM data is s will be incr	T)="1".	RAM Write)	000011		ss will be se Il be set "10 will mainta command that write a	ot by ADS 00000", be in the pre input. It the end i	ET com cause F vious a	000000 Imand. P2(ICSET) ddress
MMAND nal Signal SET P2 nal Signal Idress It w (IC: CSB CSB MMAND nal Signal	ill be set P2 SET comma	Set ac P2(IC) Addre	100000 10 Idress by ADSE SET command) Ss will be set "1 ET command. et address)	When 1 return t (RAM Write 0001 10001 T command. is refer to set 00000", becau 00000", becau When 1 addres When 1 return t	write at 22h a to 00h autorr 0 0 000000 address use P2(ICSE RAM data is s will be incr	T)="1".	RAM Write 000010 y transmitted matically. dress will be	000011		ss will be se Il be set "10 will mainta command that write a	ot by ADS 00000", be in the pre input. It the end i	ET com cause F vious a	000000 P2(ICSET) ddress tained.
MMAND nal Signal SET P2 nal Signal Idress It w (IC: CSB MMAND nal Signal SET P2 nal Signal	ill be set P2 SET comma	Set ac P2(IC) Addre	100000 10 Idress by ADSE SET command) ss will be set "1 ET command. et address)	When 1 return t (RAM Write 0001 10001 T command. is refer to set 00000", becau 00000", becau When 1 addres When 1 return t	write at 22h a to 00h autom	address, add natically.	RAM Write 000010 y transmitted matically. dress will be	000011		ss will be se Il be set "10 will mainta command that write a	et by ADSI 0000", be in the pre input. It the end i	ET com ET com ccause b vious a is maint	000000 P2(ICSET) ddress tained.
MMAND nal Signal SET P2 nal Signal Idress	ill be set P2 SET comma	Set ac P2(IC) Addre ="1" by ICSI nd cannot s	100000 10 Idress by ADSE SET command) ss will be set "1 ET command. et address)	When return t return t (RAM Write) (T command. is refer to set 00000", becau When 1 wdres When 1 wdres When 1 wdres (RAM Write)	write at 22h a to 00h autom	address, add natically.	RAM Write	000011		ss will be set "10 Will maintat command that write a RAM Write (et by ADSI 0000", be in the pre input. It the end i	ET com cause f vious a is maint	000000 P2(ICSET) ddress tained.
MMAND nal Signal SET P2 nal Signal ddress It w (IC: CSB MMAND nal Signal SET P2 nal Signal	ill be set P2 SET comma	Set ac P2(IC) Addre ="1" by ICSI nd cannot s	100000 (10 Idress by ADSE SET command) ss will be set "1 ET command. at address) 00000 (RAM Write 100000 (10	When new return to return to return to the text of the text of tex of tex of text of text of te	o (0000000 address use P2(ICSE RAM data is s will be incr write at 22h a to 00h autom 0 (000000 0 (000000 ress.)	address, add natically.	RAM Write 0000010 y transmitted matically. dress will be RAM Write 0 100000 100000 nuously trans t automatical ss, address	000011	\loc \loc	ss will be set "10 Will maintat command that write a RAM Write (et by ADSI 00007, be in the pre in the end i rit the end i RAM Write	ET com ET com ccause b is maint <u>R</u>	imand. 22(ICSET) ddress tained. AM Write 000001 tinuously ess. address

Figure 12. Address Set sequence

(3) Display control (DISCTL)

NΛ	c	D
ινι	J	D

MSB	-	·	-				LSB
D7	D6	D5	D4	D3	D2	D1	D0
С	0	1	P4	P3	P2	P1	P0

Set Frame frequency

Setting	P4	P3	Reset initialize condition
80Hz	0	0	0
71Hz	0	1	
64Hz	1	0	
53Hz	1	1	

(Note) About the characteristics of FR, refer to Oscillation characteristics.

Set LCD drive waveform

Setting	P2	Reset initialize condition
Line inversion	0	0
Frame inversion	1	

Set Power save mode

Setting	P1	P0	Reset initialize condition
Power save mode 1	0	0	
Power save mode 2	0	1	
Normal mode	1	0	0
High power mode	1	1	

(Note) VDD-VLCD≥3.0V is required for High power mode.

(Reference current consumption data)

Reset initialize condition		
×0.5		
×0.67		
×1.0		
×1.8		

(Note) Above current consumption data is reference value. It depends on panel load.

(Note) Frame frequency / LCD drive waveform / Power save mode setting will affect display image. Select the best value in point of current consumption and display image using LCD panel (under real application).

Mode	Screen flicker	Display image / contrast
Frame frequency	0	-
LCD drive waveform	0	0
Power save mode	-	0

(4) Set IC Operation (ICSET)

MSB							LSB
D7	D6	D5	D4	D3	D2	D1	D0
С	1	1	0	1	P2	P1	P0

P2: MSB data of DDRAM address. Please refer to "ADSET" command.

Setting	P2	Reset initialize condition
Address MSB'0'	0	0
Address MSB'1'	1	

Set Software Reset condition

Setting	P1
No operation	0
Software Reset	1

When "Software Reset" is executed, this LSI will be reset to initial condition.

If software reset is executed, the value of P2 and P1 will be ignored and they will be set initialized condition. (Refer to "Reset initial condition")

Switch between internal clock and external clock.

Setting	P0	Reset initialize condition
Internal clock	0	0
External clock input	1	

For internal clock : OSCIN is connected to VSS.

For external clock input: Input external clock into OSCIN.

<External Clock Frame frequency calculation>

DISCTL 80Hz select: Frame frequency [Hz] = external clock [Hz] / 512 DISCTL 71Hz select: Frame frequency [Hz] = external clock [Hz] / 576 DISCTL 64Hz select: Frame frequency [Hz] = external clock [Hz] / 648 DISCTL 53Hz select: Frame frequency [Hz] = external clock [Hz] / 768

Command		et X		
	Internal clock mode	г		
OSCIN_EN (Internal signal)			External clock mode	
Internal oscillation				
External clock (OSCIN)				

Figure 13. OSCMODE switching timing

(5) Blink control (BLKCTL)

Ν

MSB							LSB
D7	D6	D5	D4	D3	D2	D1	D0
С	1	1	1	0	*	P1	P0

Set blink condition

Setting (Hz)	P1	P0	Reset initialize condition
OFF	0	0	0
0.5	0	1	
1	1	0	
2	1	1	

(6) All pixel control (APCTL)

MSB							LSB
D7	D6	D5	D4	D3	D2	D1	D0
С	1	1	1	1	1	P1	P0

All display set ON. OFF

Setting	P1	Reset initialize condition
Normal	0	0
All pixel ON	1	

Setting	P0	Reset initialize condition
Normal	0	0
All pixel OFF	1	

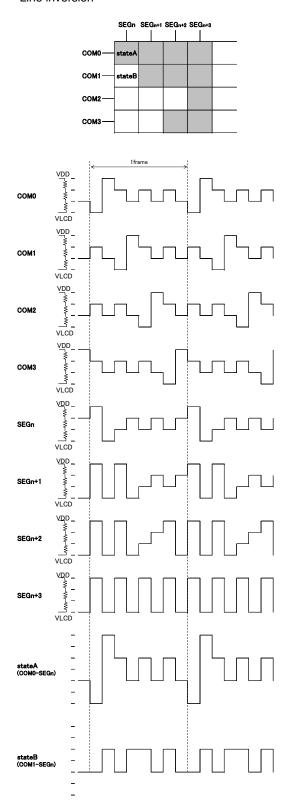
All pixels ON: All pixels are ON regardless of DDRAM data. All pixels OFF: All pixels are OFF regardless of DDRAM data.

(Note) All pixels ON/OFF is effective only at the time of "Display ON" status. The data of DDRAM do not change with this command. If both P1 and P0='1', APOFF is selected. APOFF has higher priority than APON.

Datasheet

LCD Driving Waveform

(1/3bias) Line inversion



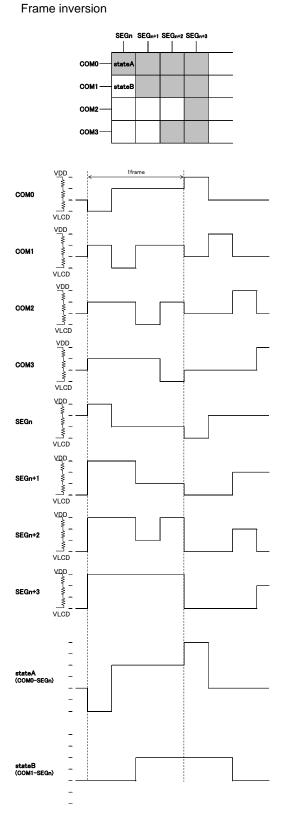


Figure 14. Line inversion waveform (1/3bias)



(1/2bias)

Line inversion

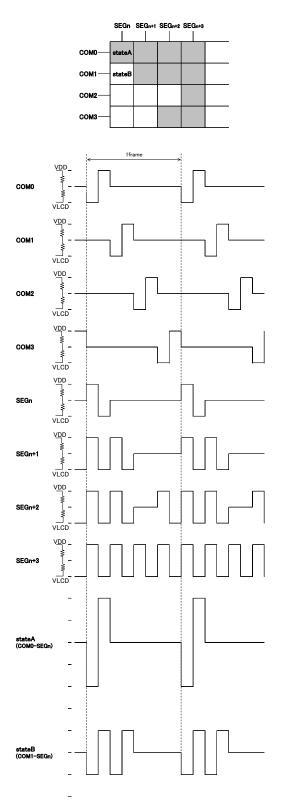
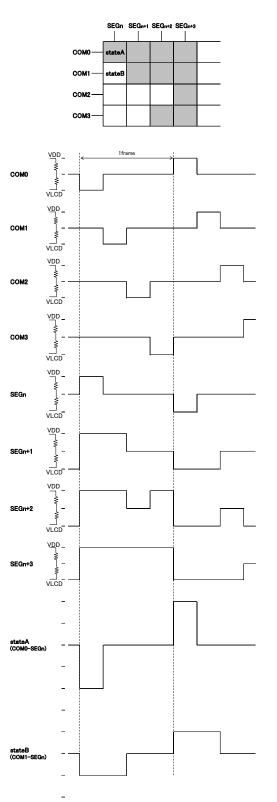


Figure 16. Line inversion waveform (1/2bias)

Frame inversion





Example of Display Data

If LCD layout pattern is shown as in Figure18, Figure19 and DDRAM data is shown as in Table 2, display pattern will be shown as in Figure 20.

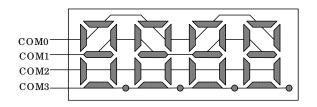


Figure 18. Example COM line pattern

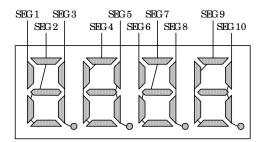


Figure 19. Example SEG line pattern



Figure 20. Example Display pattern

								-	Table	2.	DDR	AM D)ata r	nap							
		S	S	S	S	S	S	S	S	S	S	S	S	S	S	S	S	S	S	S	S
		Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е
		G	G	G	G	G	G	G	G	G	G	G	G	G	G	G	G	G	G	G	G
		0	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19
COM0	D0	0	1	1	0	1	1	1	1	0	1	0	0	0	0	0	0	0	0	0	0
COM1	D1	0	0	1	1	1	0	0	1	1	1	1	0	0	0	0	0	0	0	0	0
COM2	D2	0	0	0	1	0	1	0	0	1	0	1	0	0	0	0	0	0	0	0	0
COM3	D3	0	0	1	1	0	0	0	1	0	1	0	0	0	0	0	0	0	0	0	0
Address		00h	01h	02h	03h	04h	05h	06h	07h	08h	09h	0Ah	0Bh	0Ch	0Dh	0Eh	0Fh	10h	11h	12h	13h

Initialize Sequence

Please follow sequence below after Power-On to set this device to initial condition.

Power	on	
CSB	'H'	I/F initialize condition
CSB	'Ľ	I/F Data transfer start
↓ Execu	te So	ftware Reset by sending ICSET command

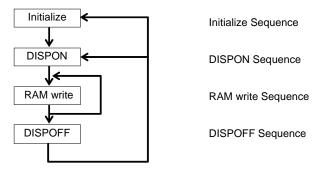
(Note) Each register value and DDRAM address, DDRAM data are random condition after power on till initialize sequence is executed.

Start Sequence

1. Start sequence example 1

No.	Input	D7	D6	D5	D4	D3	D2	D1	D0	Descriptions
1	Power on									VDD=0 to 5V (Tr=0.1ms)
	\downarrow									
2	wait 100us									Initialize IC
	\downarrow									
3	CSB 'H'									Initialize I/F data
	\downarrow									
4	CSB 'L'									I/F Data transfer start
	\downarrow									
5	ICSET	1	1	1	0	1	*	1	0	Software Reset
	\downarrow									
6	BLKCTL	1	1	1	1	0	*	0	1	
	\downarrow									
7	DISCTL	1	0	1	0	0	1	1	0	
	\downarrow									
8	ICSET	1	1	1	0	1	0	0	0	RAM address MSB set
	\downarrow									
9	ADSET	0	0	0	0	0	0	0	0	RAM address set
	\downarrow									
10	Display Data	*	*	*	*	*	*	*	*	address 00h to 01h
	Display Data	*	*	*	*	*	*	*	*	address 02h to 03h
	:									i
	Display Data	*	*	*	*	*	*	*	*	address 22h to 00h
	\downarrow									
11	CSB 'H'									I/F Data transfer stop
	\downarrow									
12	CSB 'L'									I/F Data transfer start
	\downarrow									
13	MODESET	1	1	0	*	1	0	*	*	Display ON
	\downarrow									
14	CSB 'H'									I/F Data transfer stop

2. Start sequence example 2



This LSI is initialized with Initialize Sequence. And start to display with DISPON Sequence. This LSI will update display data with RAM write Sequence.

And stop the display with DISPOFF sequence.

If you want to restart to display, This LSI will restart to display with DISPON Sequence.

Initialize sequence

Input				DA	ΤA	Description			
input	D7	D6	D5	D4	D3	D2	D1	D0	Description
Power on									
wait 100us									IC initialized
CSB 'H'									I/F initialized
CSB 'L'									
ICSET	1	1	1	0	1	0	1	0	Software Reset
MODESET	1	1	0	0	0	0	0	0	Display OFF
ADSET	0	0	0	0	0	0	0	0	RAM address set
Display Data	*	*	*	*	*	*	*	*	Display data
CSB 'H'									

DISPON sequence

Input				DA	TΑ	Description			
input	D7 D6 D5 D4 D3 D2 D1 D0							Description	
CSB 'L'									
DISCTL	1	0	1	1	1	1	1	1	Display Control
BLKCTL	1	1	1	1	0	0	0	0	BLKCTL
APCTL	1	1	1	1	1	1	0	0	APCTL
MODESET	1	1	0	0	1	0	0	0	Display ON
CSB 'H'									

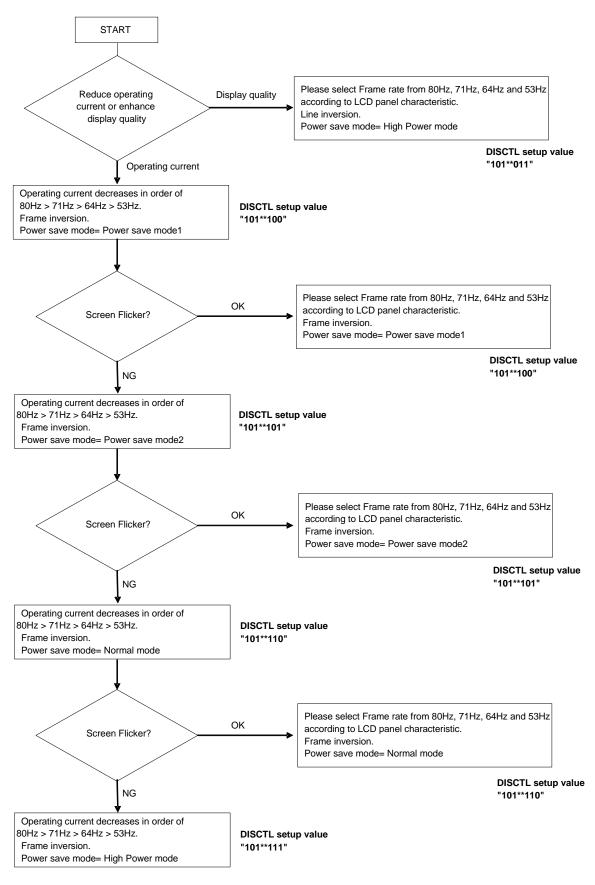
RAM write sequence

Input				DA	TΑ	Description			
input	D7	D6	D5	D4	D3	D2	D1	D0	Description
CSB 'L'									
DISCTL	1	0	1	1	1	1	1	1	Display Control
BLKCTL	1	1	1	1	0	0	0	0	BLKCTL
APCTL	1	1	1	1	1	1	0	0	APCTL
MODESET	1	1	0	0	1	0	0	0	Display ON
ADSET	0	0	0	0	0	0	0	0	RAM address set
Display Data	*	*	*	*	*	*	*	*	Display data
CSB 'H'									

DISPOFF sequence

Input	DATA								Description	
input	D7	D6	D5	D4	D3	D2	D1	D0	Description	
CSB 'L'										
MODESET CSB 'H'	1	1	0	0	0	0	0	0	Display OFF	
MODESET CSB 'H'	1	1	0	0	0	0	0	0	Display OFF	

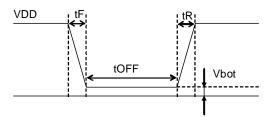
Example of Start Sequence



Cautions on Power ON Condition

This LSI has "P.O.R" (Power-On Reset) circuit and Software Reset function. Please keep the following recommended Power-On conditions in order to power up properly.

Please set power up conditions to meet the recommended tR, tF, tOFF, and Vbot spec below in order to ensure P.O.R operation.



Recommended condition of tR,tF,tOFF and Vbot							
tR tF tOFF Vbot							
Less than	Less than	More than	Less than				
1ms	1ms	150ms	0.1V				

Figure 21. Power ON/OFF waveform

If it is difficult to meet above conditions, execute the following sequence after Power-On. Command input is not accepted during power off. It has to take care that software reset is not a perfect substitute to POR function.

(1) CSB="L" \rightarrow "H" condition

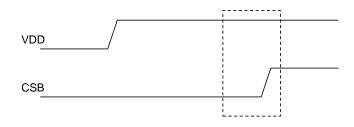
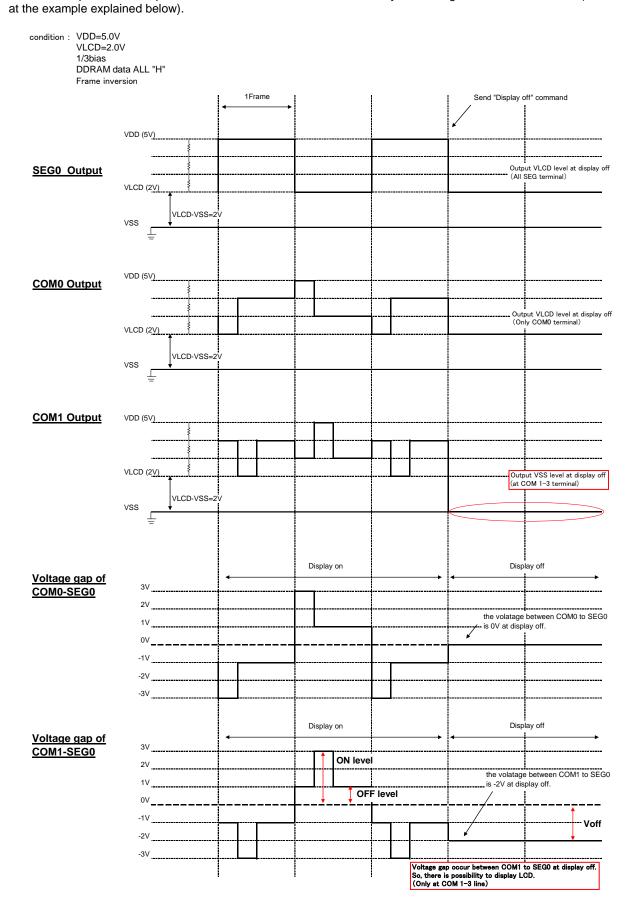


Figure 22. CSB Timing

(2) After CSB"H"→"L", execute Software Reset (ICSET command).

Cautions on Application

In case, BU9795AFV-LB used at VLCD≠VSS, voltage gap occur between SEG line to COM1–3 line at Display off state. Because of this voltage gap, there is possibility to display LCD for a moment. To avoid this phenomenon, please decide VDD and VLCD level to satisfy Voff voltage lower than OFF level (OFF level = 1V



Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. The absolute maximum rating of the Pd stated in this specification is when the IC is mounted on a 70mm x 70mm x 1.6mm glass epoxy board. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

Operational Notes – continued

11. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

12. Regarding the Input Pin of the IC

In the construction of this IC, P-N junctions are inevitably formed creating parasitic diodes or transistors. The operation of these parasitic elements can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions which cause these parasitic elements to operate, such as applying a voltage to an input pin lower than the ground voltage should be avoided. Furthermore, do not apply a voltage to the input pins when no power supply voltage is applied to the IC. Even if the power supply voltage is applied, make sure that the input pins have voltages within the values specified in the electrical characteristics of this IC.

13. Ceramic Capacitor

When using a ceramic capacitor, determine the dielectric constant considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

14. Area of Safe Operation (ASO)

Operate the IC such that the output voltage, output current, and power dissipation are all within the Area of Safe Operation (ASO).

15. Thermal Shutdown Circuit(TSD)

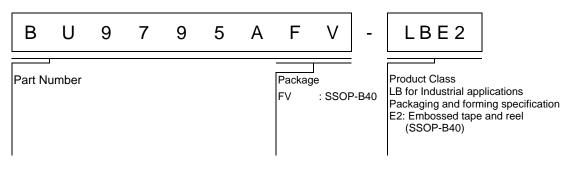
This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's power dissipation rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF all output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.

Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

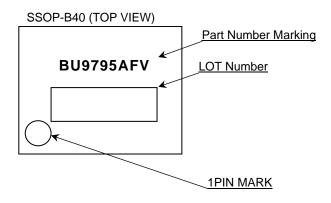
16. Over Current Protection Circuit (OCP)

This IC incorporates an integrated overcurrent protection circuit that is activated when the load is shorted. This protection circuit is effective in preventing damage due to sudden and unexpected incidents. However, the IC should not be used in applications characterized by continuous operation or transitioning of the protection circuit.

Ordering Information



Marking Diagram



Physical Dimension Tape and Reel Information Package Name SSOP-B40 $1 \ 3. \ 6 \pm 0. \ 2$ (Max 13.95 (include. BURR) 40 21A AA က N 8 ± 0 . 4 ± 0 2 0 2. 1+ 10 5 0 Ħ Π Π Н 20 1 **1PIN MARK** $0.\ 1\ 5\pm 0.\ 1$ Г $8\pm0.$ (UNIT;mm) ÷ -PKG:SSOP-B40 0. 0.65 0. $22\pm 0.1 \oplus 0.08$ $\bigcirc 0.1S$ 図番; EX157-5001 <Tape and Reel information> Embossed carrier tape Tape Quantity 2000pcs E2 Direction The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand of feed Direction of feed 1pin Reel *Order quantity needs to be multiple of the minimum quantity

Revision History

Date	Revision	Changes			
23.Aug.2013	001	New Release			
26.Feb.2014	002	Delete sentence "and log life cycle" in General Description and Futures. Applied new style (change of the size of the title).			

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JAPAN	USA	EU	CHINA
CLASSI	CLASSⅢ	CLASS II b	CLASSⅢ
CLASSⅣ	CLASSI	CLASSⅢ	

2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:

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[b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure

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 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
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 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
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- 8. Confirm that operation temperature is within the specified range described in the product specification.
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 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
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